Philips Semiconductors Product specification

Low power quad op amps

LM124/224/324/324A/ SA534/LM2902

DESCRIPTION

The LM124/SA534/LM2902 series consists of four independent, high-gain, internally frequency-compensated operational amplifiers designed specifically to operate from a single power supply over a wide range of voltages.

UNIQUE FEATURES

In the linear mode, the input common-mode voltage range includes ground and the output voltage can also swing to ground, even though operated from only a single power supply voltage.

The unity gain crossover frequency and the input bias current are temperature-compensated.

FEATURES

- Internally frequency-compensated for unity gain
- Large DC voltage gain: 100dB
- Wide bandwidth (unity gain): 1MHz (temperature-compensated)
- Wide power supply range Single supply: 3V_{DC} to 30V_{DC} or dual supplies: ±1.5V_{DC} to ±15V_{DC}
- Very low supply current drain: essentially independent of supply voltage (1mW/op amp at +5V_{DC})
- Low input biasing current: 45nA_{DC} (temperature-compensated)
- Low input offset voltage: 2mV_{DC} and offset current: 5nA_{DC}
- Differential input voltage range equal to the power supply voltage
- Large output voltage: 0V_{DC} to V_{CC}-1.5V_{DC} swing

PIN CONFIGURATION

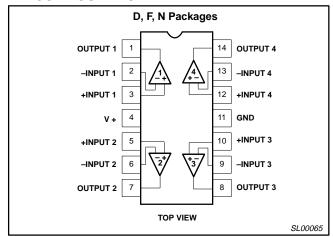


Figure 1. Pin Configuration

ORDERING INFORMATION

DESCRIPTION	TEMPERATURE RANGE	ORDER CODE	DWG #
14-Pin Plastic Dual In-Line Package (DIP)	-55°C to +125°C	LM124N	SOT27-1
14-Pin Ceramic Dual In-Line Package (CERDIP)	-55°C to +125°C	LM124F	0581B
14-Pin Plastic Dual In-Line Package (DIP)	-25°C to +85°C	LM224N	SOT27-1
14-Pin Ceramic Dual In-Line Package (CERDIP)	-25°C to +85°C	LM224F	0581B
14-Pin Plastic Small Outline (SO) Package	-25°C to +85°C	LM224D	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	0°C to +70°C	LM324N	SOT27-1
14-Pin Ceramic Dual In-Line Package (CERDIP)	0°C to +70°C	LM324F	0581B
14-Pin Plastic Small Outline (SO) Package	0°C to +70°C	LM324D	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	0°C to +70°C	LM324AN	SOT27-1
14-Pin Plastic Small Outline (SO) Package	0°C to +70°C	LM324AD	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	-40°C to +85°C	SA534N	SOT27-1
14-Pin Ceramic Dual In-Line Package (CERDIP)	-40°C to +85°C	SA534F	0581B
14-Pin Plastic Small Outline (SO) Package	-40°C to +85°C	SA534D	SOT108-1
14-Pin Plastic Small Outline (SO) Package	-40°C to +125°C	LM2902D	SOT108-1
14-Pin Plastic Dual In-Line Package (DIP)	-40°C to +125°C	LM2902N	SOT27-1

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ABSOLUTE MAXIMUM RATINGS

SYMBOL	PARAMETER	RATING	UNIT	
V _{CC}	Supply voltage	32 or ±16	V _{DC}	
V _{IN}	Differential input voltage	32	V _{DC}	
V _{IN}	Input voltage	-0.3 to +32	V _{DC}	
P _D	Maximum power dissipation, T _A =25°C (still-air) ¹			
	N package	1420	mW	
	F package	1190	mW	
	D package	1040	mW	
	Output short-circuit to GND one amplifier ² V _{CC} <15V _{DC} and T _A =25°C	Continuous		
I _{IN}	Input current (V _{IN} <-0.3V) ³	50	mA	
T _A	Operating ambient temperature range LM324/A LM224 SA534	0 to +70 -25 to +85 -40 to +85	ဝံ ဝံ ဝံ	
	LM2902 LM124	-40 to +125 -55 to +125	ô ô	
T _{STG}	Storage temperature range	-65 to +150	°C	
T _{SOLD}	Lead soldering temperature (10sec max)	300	°C	

NOTES

1. Derate above 25°C at the following rates:

F package at 9.5mW/°C

N package at 11.4mW/°C

D package at 8.3mW/°C

- Short-circuits from the output to V_{CC}+ can cause excessive heating and eventual destruction. The maximum output current is approximately 40mA, independent of the magnitude of V_{CC}. At values of supply voltage in excess of +15V_{DC} continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction.
 This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the
- 3. This input current will only exist when the voltage at any of the input leads is driven negative. It is due to the collector-base junction of the input PNP transistors becoming forward biased and thereby acting as input bias clamps. In addition, there is also lateral NPN parasitic transistor action on the IC chip. This action can cause the output voltages of the op amps to go to the V+ rail (or to ground for a large overdrive) during the time that the input is driven negative.

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DC ELECTRICAL CHARACTERISTICS

V_{CC}=5V, T_A=25°C unless otherwise specified.

SYMBOL	PARAMETER	TEST CONDITIONS	LM124/LM224		LM324/SA534/LM2902		UNIT		
			Min	Тур	Max	Min	Тур	Max	וואט [
V _{OS} Offset voltage ¹	Officet violtogia 1	R _S =0Ω		±2	±5		±2	±7	mV
	Offset voltage	$R_S=0\Omega$, over temp.			±7			±9	IIIV
ΔV _{OS} /ΔT	Temperature drift	$R_S=0\Omega$, over temp.		7			7		μV/°(
	Input current ²	I _{IN} (+) or I _{IN} (-)		45	150		45	250	nA
BIAS	Input current	$I_{IN}(+)$ or $I_{IN}(-)$, over temp.		40	300		40	500	
ΔΙ _{ΒΙΑS} /ΔΤ	Temperature drift	Over temp.		50			50		pA/°0
los	Offset current	l _{IN} (+)-l _{IN} (-)		±3	±30		±5	±50	nA
	Oliset current	$I_{IN}(+)$ - $I_{IN}(-)$, over temp.			±100			±150	11/1
ΔI _{OS} /ΔT	Temperature drift	Over temp.		10			10		pA/°(
N /	Common-mode voltage	V _{CC} ≤30V	0		V _{CC} -1.5	0		V _{CC} -1.5	.,
V_{CM}	range ³	V _{CC} ≤30V, over temp.	0		V _{CC} -2	0		V _{CC} -2	V
CMRR	Common-mode rejection ratio	V _{CC} =30V	70	85		65	70		dB
V _{OUT}	Output voltage swing	R_L =2kΩ, V_{CC} =30V, over temp.	26			26			V
V _{OH}	Output voltage high	R_L ≤10kΩ, V_{CC} =30V, over temp.	27	28		27	28		V
V _{OL}	Output voltage low	$R_L \le 10k\Omega$, over temp.		5	20		5	20	m∨
I _{CC}	Supply current	R _L =∞, V _{CC} =30V, over temp.		1.5	3		1.5	3	mA
		R _L =∞, over temp.		0.7	1.2		0.7	1.2	
A _{VOL}	Large-signal voltage gain	V_{CC} =15V (for large V_{O} swing), R_{L} ≥2k Ω	50	100		25	100		V/mV
		V_{CC} =15V (for large V_{O} swing), R_{L} $\ge 2k\Omega$, over temp.	25			15			
	Amplifier-to-amplifier coupling ⁵	f=1kHz to 20kHz, input referred		-120			-120		dB
PSRR	Power supply rejection ratio	R _S ≤0Ω	65	100		65	100		dB
l _{оит}	Output current source	V _{IN} +=+1V, V _{IN} -=0V, V _{CC} =15V	20	40		20	40		
		V _{IN} +=+1V, V _{IN} -=0V, V _{CC} =15V, over temp.	10	20		10	20		
	Output current	V _{IN} -=+1V, V _{IN} +=0V, V _{CC} =15V	10	20		10	20		mA
	sink	V _{IN} -=+1V, V _{IN} +=0V, V _{CC} =15V, over temp.	5	8		5	8		
		V _{IN} -=+1V, V _{IN} +=0V, V _O =200mV	12	50		12	50		μΑ
sc	Short-circuit current ⁴		10	40	60	10	40	60	mA
GBW	Unity gain bandwidth			1			1		MHz
SR	Slew rate			0.3			0.3		V/µs
V _{NOISE}	Input noise voltage	f=1kHz		40			40		nV/√l
V_{DIFF}	Differential input voltage ³				V_{CC}			V _{CC}	V

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DC ELECTRICAL CHARACTERISTICS (Continued)

V_{CC}=5V, T_A=25°C unless otherwise specified.

CVMPOL	PARAMETER	TEST CONDITIONS	LM324A			LINUT	
SYMBOL		TEST CONDITIONS	Min	Тур	Max	UNIT	
.,	Office to the seal	R _S =0Ω		±2	±3	\/	
Vos	Offset voltage ¹	$R_S=0\Omega$, over temp.			±5	mV	
ΔV _{OS} /ΔΤ	Temperature drift	$R_S=0\Omega$, over temp.		7	30	μV/°C	
		l _{IN} (+) or l _{IN} (-)		45	100	•	
BIAS	Input current ²	I _{IN} (+) or I _{IN} (-), over temp.		40	200	nA	
ΔΙ _{ΒΙΑS} /ΔΤ	Temperature drift	Over temp.		50		pA/°C	
	0" .	l _{IN} (+)-l _{IN} (-)		±5	±30		
los	Offset current	I _{IN} (+)-I _{IN} (-), over temp.			±75	nA	
ΔI _{OS} /ΔT	Temperature drift	Over temp.		10	300	pA/°C	
V _{CM}	Common-mode voltage range ³	V _{CC} ≤30V	0		V _{CC} -1.5	V	
		V _{CC} ≤30V, over temp.	0		V _{CC} -2	V	
CMRR	Common-mode rejection ratio	V _{CC} =30V	65	85		dB	
V _{OUT}	Output voltage swing	R _L =2kΩ, V _{CC} =30V, over temp.	26			V	
V _{OH}	Output voltage high	R _L ≤10kΩ, V _{CC} =30V, over temp.	27	28		V	
V _{OL}	Output voltage low	R _L ≤10kΩ, over temp.		5	20	mV	
I _{CC}	Supply current	R _L =∞, V _{CC} =30V, over temp.		1.5	3	mA	
		R _L =∞, over temp.		1.2	mA		
A _{VOL}	Large-signal voltage gain	V _{CC} =15V (for large V _O swing), R _L ≥2kΩ	25	100		V/mV	
VOL		V_{CC} =15V (for large V_O swing), R_L ≥2k $Ω$, over temp.	15			V/mV	
	Amplifier-to-amplifier coupling ⁵	ier-to-amplifier coupling ⁵ f=1kHz to 20kHz, input referred -120		dB			
PSRR	Power supply rejection ratio	R _S ≤0Ω	65	100		dB	
	Output current source	V _{IN} +=+1V, V _{IN} -=0V, V _{CC} =15V	20	40		mA	
		V _{IN} +=+1V, V _{IN} -=0V, V _{CC} =15V, over temp.	10	20		mA	
l _{out}	Output current	V _{IN} -=+1V, V _{IN} +=0V, V _{CC} =15V	10	20		mA	
	sink	V _{IN} -=+1V, V _{IN} +=0V, V _{CC} =15V, over temp.	5	8		mA	
		V _{IN} -=+1V, V _{IN} +=0V, V _O =200mV	12	50		μΑ	
sc	Short-circuit current ⁴		10	40	60	mA	
V _{DIFF}	Differential input voltage ³				V _{CC}	V	
GBW	Unity gain bandwidth			1		MHz	
SR	Slew rate			0.3		V/µs	
V _{NOISE}	Input noise voltage	f=1kHz		40	1 1	nV/√Hz	

- 1. $V_O \approx 1.4 V_{DC}$, $R_S = 0\Omega$ with V_{CC} from 5V to 30V and over full input common-mode range (0V $_{DC}$ + to V $_{CC}$ -1.5V). 2. The direction of the input current is out of the IC due to the PNP input stage. This current is essentially constant, independent of the state of the output so no loading change exists on the input lines.
- 3. The input common-mode voltage or either input signal voltage should not be allowed to go negative by more than 0.3V. The upper end of the common-mode voltage range is V_{CC} -1.5, but either or both inputs can go to +32V without damage. Short-circuits from the output to V_{CC} can cause excessive heating and eventual destruction. The maximum output current is approximately
- 40mA independent of the magnitude of V_{CC}. At values of supply voltage in excess of +15V_{DC}, continuous short-circuits can exceed the power dissipation ratings and cause eventual destruction. Destructive dissipation can result from simultaneous shorts on all amplifiers.
- 5. Due to proximity of external components, insure that coupling is not originating via stray capacitance between these external parts. This typically can be detected as this type of coupling increases at higher frequencies.

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EQUIVALENT CIRCUIT

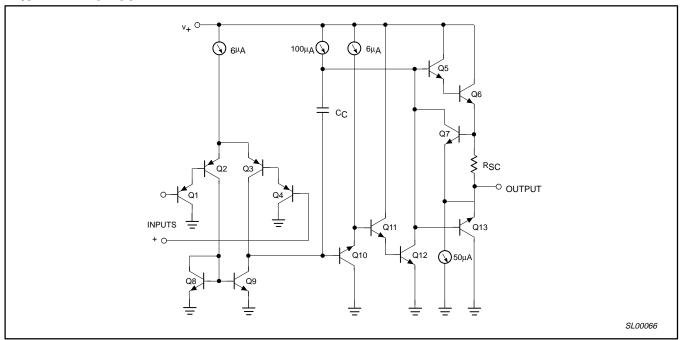


Figure 2. Equivalent Circuit

TYPICAL PERFORMANCE CHARACTERISTICS

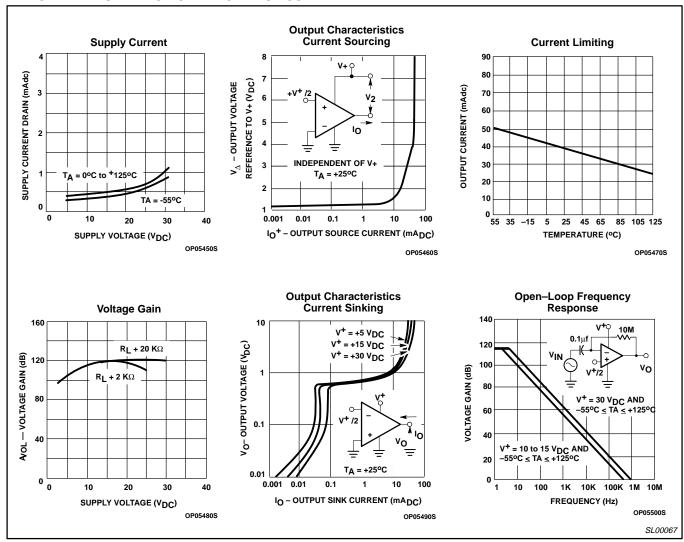


Figure 3. Typical Performance Characteristics

TYPICAL PERFORMANCE CHARACTERISTICS (Continued)

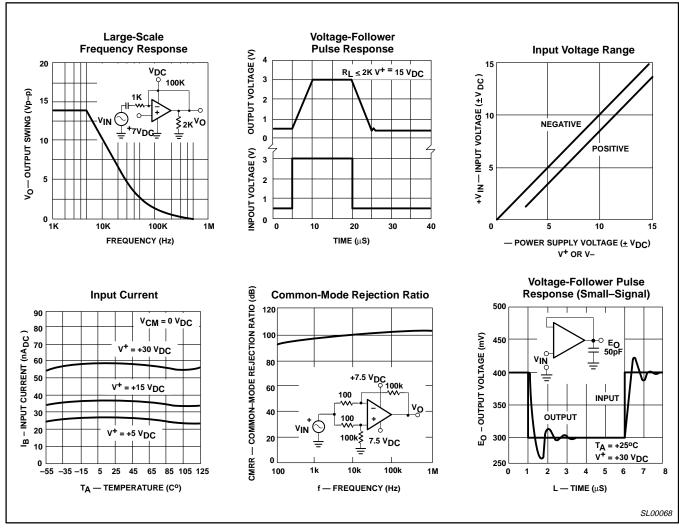


Figure 4. Typical Performance Characteristics (cont.)

TYPICAL APPLICATIONS

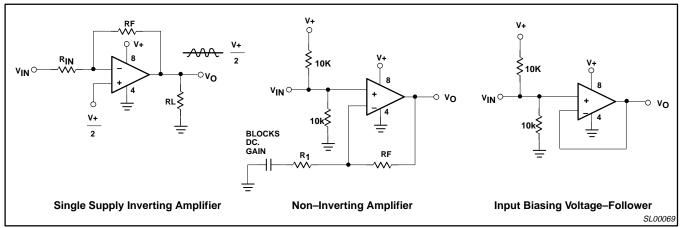


Figure 5. Typical Applications

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